

The RF Line

NPN Silicon

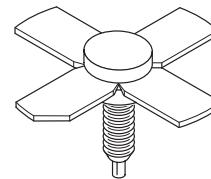
RF Power Transistor

... designed primarily for wideband large-signal driver and predriver amplifier stages in the 200–500 MHz frequency range.

- Guaranteed Performance at 400 MHz, 28 V
Output Power = 20 Watts
Power Gain = 10 dB Min
Efficiency = 50% Min
- 100% Tested for Load Mismatch at all Phase Angles with 30:1 VSWR
- Gold Metallization System for High Reliability
- Computer-Controlled Wirebonding Gives Consistent Input Impedance

MRF323

20 W, 400 MHz
RF POWER
TRANSISTOR
NPN SILICON



CASE 244-04, STYLE 1

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	33	Vdc
Collector-Base Voltage	V_{CBO}	60	Vdc
Emitter-Base Voltage	V_{EBO}	4.0	Vdc
Collector Current — Continuous — Peak	I_C	2.2 3.0	Adc
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ (1) Derate above 25°C	P_D	55 310	Watts mW/ $^\circ\text{C}$
Storage Temperature Range	T_{stg}	-65 to +150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	3.2	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit

OFF CHARACTERISTICS

Collector-Emitter Breakdown Voltage ($I_C = 20 \text{ mA}\text{dc}$, $I_B = 0$)	$V_{(BR)CEO}$	33	—	—	Vdc
Collector-Emitter Breakdown Voltage ($I_C = 20 \text{ mA}\text{dc}$, $V_{BE} = 0$)	$V_{(BR)CES}$	60	—	—	Vdc
Collector-Base Breakdown Voltage ($I_C = 20 \text{ mA}\text{dc}$, $I_E = 0$)	$V_{(BR)CBO}$	60	—	—	Vdc
Emitter-Base Breakdown Voltage ($I_E = 2.0 \text{ mA}\text{dc}$, $I_C = 0$)	$V_{(BR)EBO}$	4.0	—	—	Vdc
Collector Cutoff Current ($V_{CB} = 30 \text{ Vdc}$, $I_E = 0$)	I_{CBO}	—	—	2.0	mAdc

ON CHARACTERISTICS

DC Current Gain ($I_C = 1.0 \text{ Adc}$, $V_{CE} = 5.0 \text{ Vdc}$)	h_{FE}	20	—	80	—

NOTE:

(continued)

1. This device is designed for RF operation. The total device dissipation rating applies only when the device is operated as an RF amplifier.

tyco / Electronics

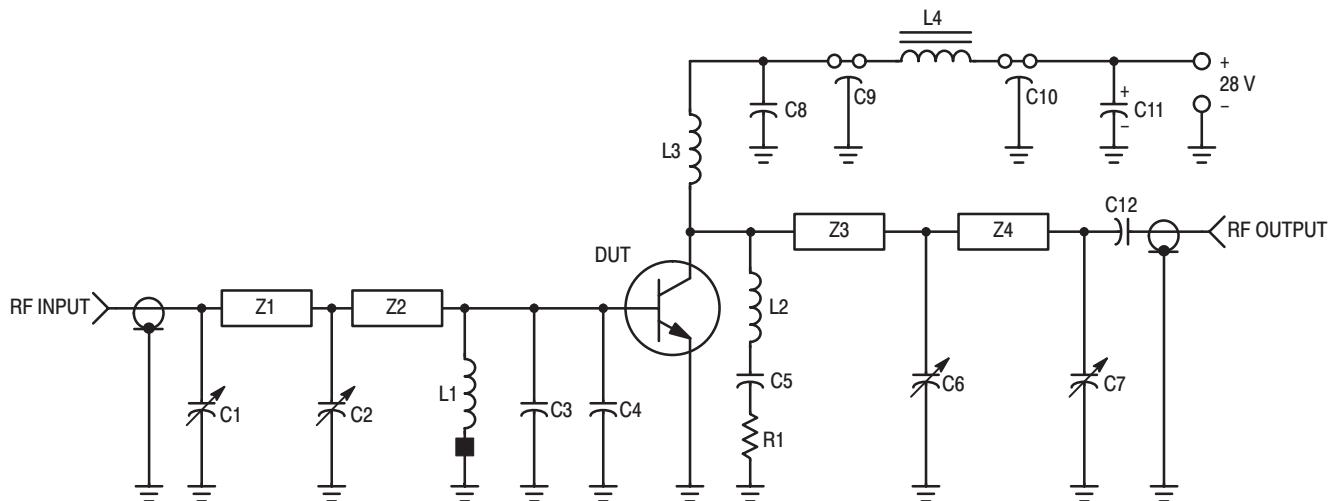
M/A-COM

ELECTRICAL CHARACTERISTICS — continued ($T_C = 25^\circ\text{C}$ unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
DYNAMIC CHARACTERISTICS					
Output Capacitance ($V_{CB} = 28 \text{ Vdc}$, $I_E = 0$, $f = 1.0 \text{ MHz}$)	C_{ob}	—	20	24	pF

FUNCTIONAL TESTS (Figure 1)

Common-Emitter Amplifier Power Gain ($V_{CC} = 28 \text{ Vdc}$, $P_{out} = 20 \text{ W}$, $f = 400 \text{ MHz}$)	G_{PE}	10	11	—	dB
Collector Efficiency ($V_{CC} = 28 \text{ Vdc}$, $P_{out} = 20 \text{ W}$, $f = 400 \text{ MHz}$)	η	50	60	—	%
Load Mismatch ($V_{CC} = 28 \text{ Vdc}$, $P_{out} = 20 \text{ W}$, $f = 400 \text{ MHz}$, VSWR = 30:1 all phase angles)	Ψ	No Degradation in Output Power			



C1, C2, C6 — 1.0–20 pF Johanson Trimmer (JMC 5501)

C3, C4 — 47 pF ATC Chip Capacitor

C5, C8 — 0.1 μF Erie Redcap

C7 — 0.5–10 pF Johanson Trimmer (JMC 5201)

C9, C10 — 680 pF Feedthru

C11 — 1.0 μF 50 Volt Tantalum

C12 — 0.018 μF Vitramon Chip Capacitor

L1 — 0.33 μH Molded Choke with Ferroxcube Bead
(Ferroxcube 56-590-65/4B) on Ground End

L2 — 6 Turns #20 Enamel, 1/4" ID, Closewound

L3 — 4 Turns #20 Enamel, 1/8" ID, Closewound

L4 — Ferroxcube VK200-19/4B

R1 — 5.1 Ω 1/4 Watt

Z1 — Microstrip 0.1" W x 1.35" L

Z2 — Microstrip 0.1" W x 0.55" L

Z3 — Microstrip 0.1" W x 0.8" L

Z4 — Microstrip 0.1" W x 1.75" L

Board — Glass Teflon $\epsilon_r = 2.56$, $t = 0.062"$

Input/Output Connectors — Type N

Figure 1. 400 MHz Test Circuit Schematic

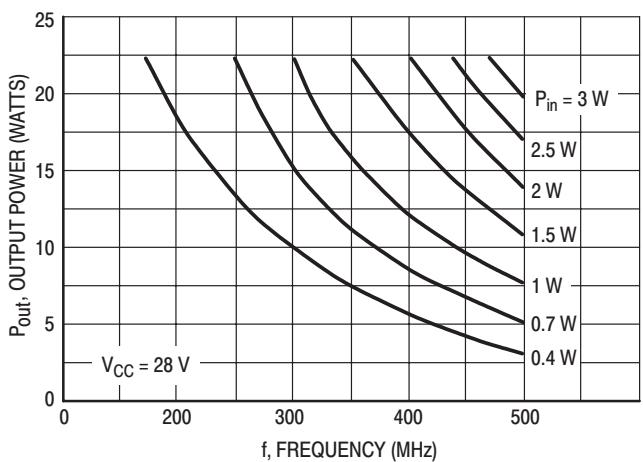


Figure 2. Output Power versus Frequency

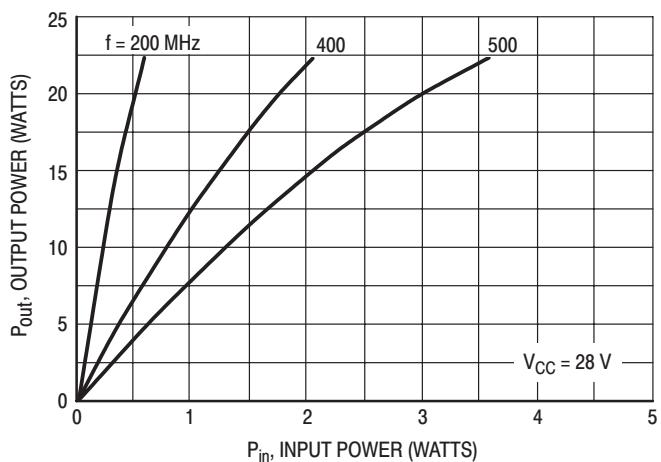


Figure 3. Output Power versus Input Power

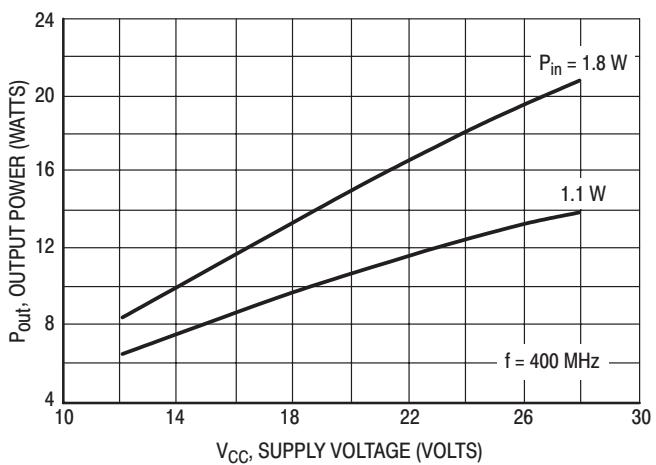


Figure 4. Output Power versus Supply Voltage

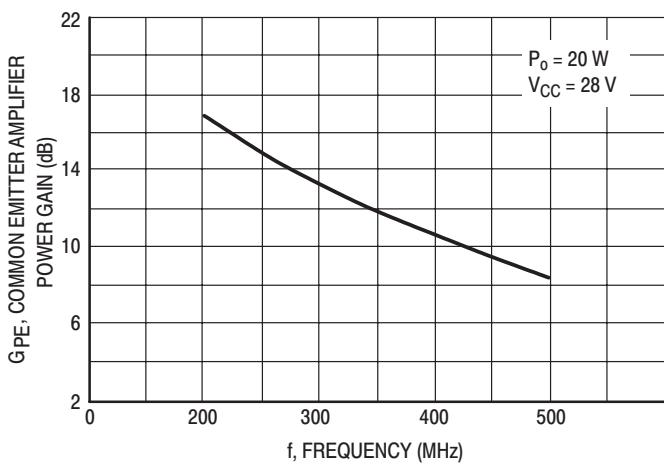


Figure 5. Power Gain versus Frequency

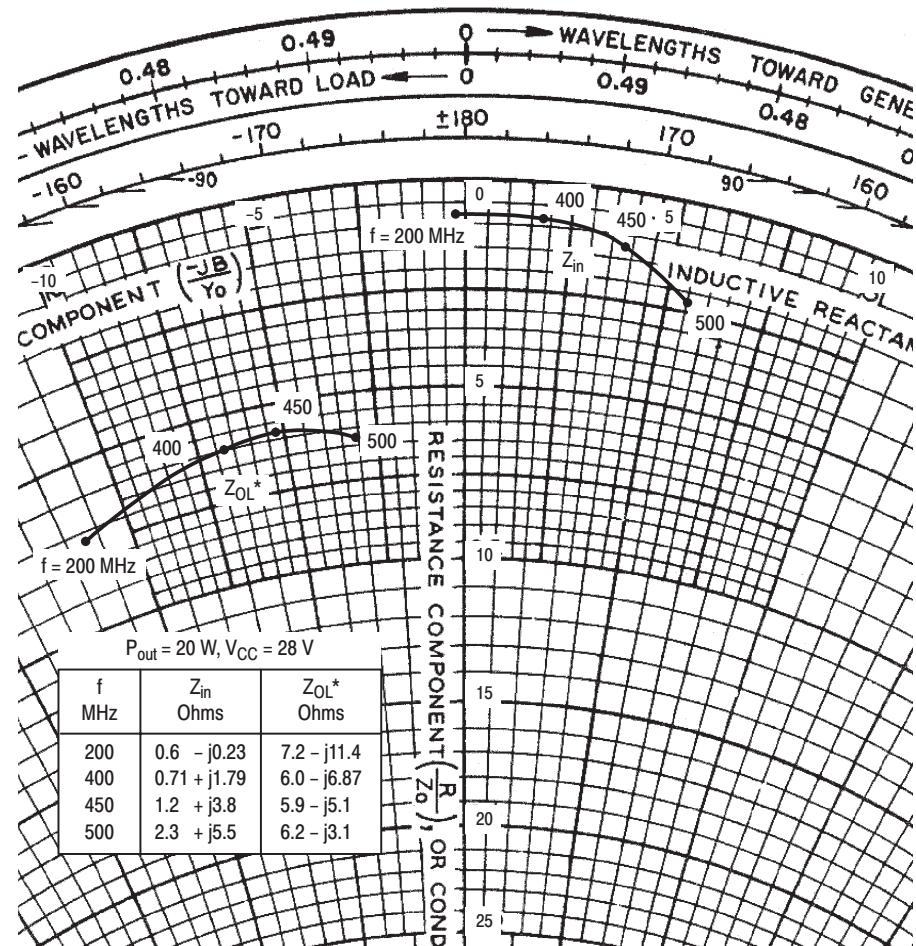
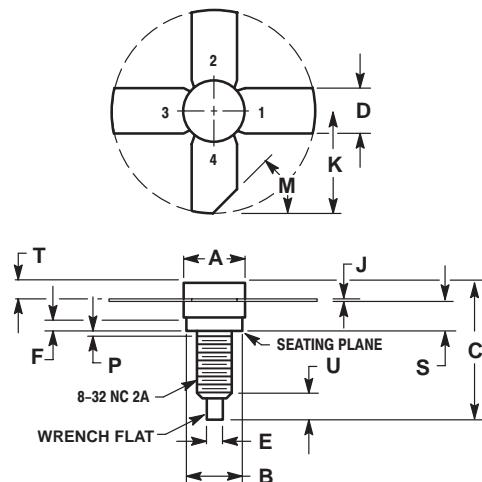


Figure 6. Series Equivalent Impedance

PACKAGE DIMENSIONS



DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	7.06	7.26	0.278	0.286
B	6.20	6.50	0.244	0.256
C	14.99	16.51	0.590	0.650
D	5.46	5.96	0.215	0.235
E	1.40	1.65	0.055	0.065
G	1.52	---	0.060	---
J	0.08	0.17	0.003	0.007
K	11.05	---	0.435	---
M	45° NOM		45° NOM	
P	---	1.27	---	0.050
S	3.00	3.25	0.118	0.128
T	1.40	1.77	0.055	0.070
U	2.92	3.68	0.115	0.145

STYLE 1:
 PIN 1. Emitter
 2. Base
 3. Emitter
 4. Collector

CASE 244-04
ISSUE J

Specifications subject to change without notice.

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